

Hyperfast Rectifier, 2 x 3 A FRED Pt®





LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | | | |
|----------------------------------|-------------------|--|--|--|--|--|--|
| I _{F(AV)} 2 x 3 A | | | | | | | |
| V _R | 200 V | | | | | | |
| V _F at I _F | 0.71 V | | | | | | |
| t _{rr} | 25 ns | | | | | | |
| T _J max. | 175 °C | | | | | | |
| Package | FlatPAK 5 x 6 | | | | | | |
| Circuit configuration | Separated cathode | | | | | | |

FEATURES

• Hyper fast recovery time, reduced Q_{rr}, and soft recovery



HALOGEN

FREE

• 175 °C maximum operating junction temperature

Low forward voltage drop

· Low leakage current

- Specific for output and snubber operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyper fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, boost, lighting, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: FlatPAK 5 x 6

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002, meets JESD 201 class 2 whisker test

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|-------------------------------------------|------------------------|------------------------------------------------|--------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 200 | | | | |
| Average rectified forward current per dev | ioo I | T _{Solderpad} = 170 °C, DC | 3 | V | | | |
| Average rectilled forward current per dev | ICE I _{F(AV)} | T _{Solderpad} = 169 °C, D = 0.5 | 3 | | | | |
| Non-repetitive peak surge current per dev | | T _J = 25 °C, 10 ms sinusoidal pulse | 147 | ٨ | | | |
| per dic | de I _{FSM} | | 70 | Α | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|--------------------------------------------------------------------------------------|-----------------|----------------------------------------------------------------|-----|------|------|----|--|--|
| PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. | | | | | | | | |
| Breakdown voltage, blocking voltage | V_{BR}, V_{R} | I _R = 100 μA | 200 | - | - | | | |
| Forward voltage | | I _F = 3 A | - | 0.88 | 0.94 | V | | |
| | V _F | I _F = 3 A, T _J = 150 °C | - | 0.71 | 0.74 | | | |
| Developed legisers of the second | | V _R = V _R rated | - | - | 2 | | | |
| Reverse leakage current | I _R | T _J = 150 °C, V _R = V _R rated | - | 6 | 40 | μA | | |
| Junction capacitance | C _T | V _R = 200 V | - | 14 | - | pF | | |



| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|---------------------------------------------------------------------------------------------|--------------------|-------------------------------------------------------------------|---------------------------------------------------------------------------------------|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = 50$ | 0 A/μs, V _R = 30 V | - | 26 | - | | |
| Reverse recovery time | t _{rr} | $I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$ | | - | - | 25 | | |
| | | T _J = 25 °C | $I_F = 3 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$ | - | 15 | - | ns | |
| | | T _J = 125 °C | | - | 25 | - | | |
| Peak recovery current | I _{RRM} - | T _J = 25 °C | | - | 2 | - | Α | |
| | | T _J = 125 °C | | - | 3 | - | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | = | 12 | - | 200 | |
| | Q_{rr} | T _J = 125 °C | | - | 40 | - | nC | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | |
|------------------------------------------------|-----------------------------------|-----------------|------|------|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C | | | |
| Thermal resistance, junction to ambient | R _{thJA} (1)(2) | | - | 90 | 103 | | | | |
| Thermal resistance, junction to mount | R _{thJM} (3) | | - | 2.3 | 2.6 | °C/W | | | |

Notes

- $^{(1)}$ The heat generated must be less than thermal conductivity from junction to ambient; $dP_D/dT_J < 1 \ x \ R_{thJA}$
- $^{(2)}$ Free air, mounted or recommended copper pad area; thermal resistance R_{thJA} junction to ambient
- (3) Mounted on infinite heatsink

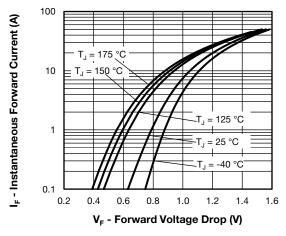


Fig. 1 - Typical Forward Voltage Drop Characteristics

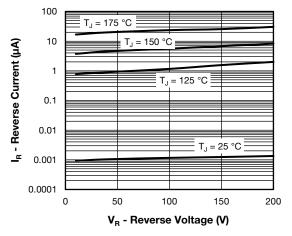


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

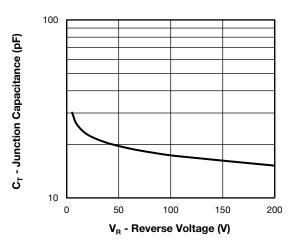


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

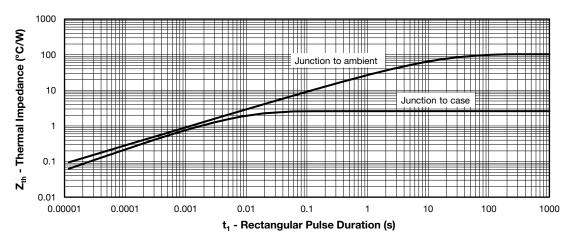


Fig. 4 - Maximum Thermal Impedance Zth Characteristics

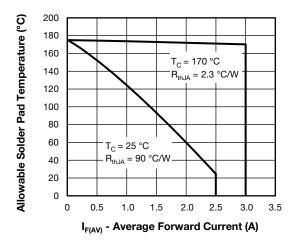


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

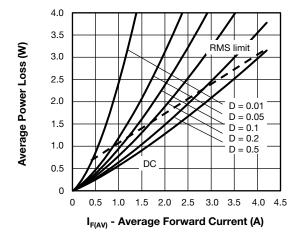


Fig. 6 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see Fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

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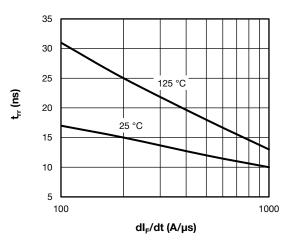


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

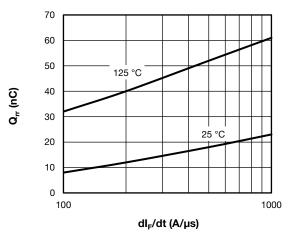
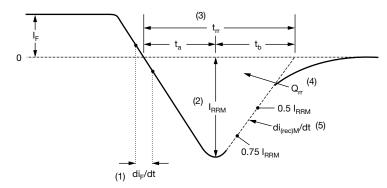


Fig. 8 - Typical Stored Charge vs. dl_E/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_{r}$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

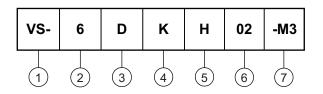
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (6 = 6 A)

Circuit configuration:

D = separated cathode

K = FlatPAK package

5 - Process type:

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

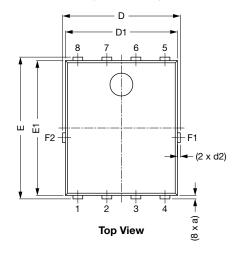
7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

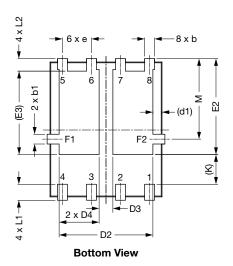
| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|--------------------|------------------------|---------------|-----------------------------------|--|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-6DKH02-M3/H | 0.10 | Н | 1500 | 7"diameter plastic tape and reel | | | | |
| VS-6DKH02-M3/I | 0.10 | I | 6000 | 13"diameter plastic tape and reel | | | | |

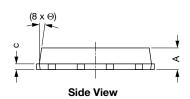
| LINKS TO RELATED DOCUMENTS | | | | | | |
|--------------------------------------------|--------------------------|--|--|--|--|--|
| Dimensions <u>www.vishay.com/doc?96056</u> | | | | | | |
| Part marking information | www.vishay.com/doc?96059 | | | | | |
| Packaging information | www.vishay.com/doc?88869 | | | | | |
| SPICE model | www.vishay.com/doc?96882 | | | | | |

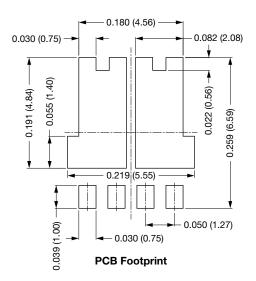
FlatPAK 5 x 6 (Dual)

DIMENSIONS in inches (millimeters)









| DIM | | INCHES | | | MILLIMETERS | | | |
|------|-------|--------|-------|------|-------------|------|--|--|
| DIM. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | | |
| Α | 0.035 | 0.039 | 0.043 | 0.89 | 0.99 | 1.09 | | |
| (a) | - | 0.006 | - | - | 0.15 | - | | |
| b | 0.013 | 0.017 | 0.020 | 0.32 | 0.43 | 0.52 | | |
| b1 | 0.013 | 0.017 | 0.020 | 0.32 | 0.43 | 0.52 | | |
| С | 0.008 | - | 0.014 | 0.20 | - | 0.35 | | |
| D | 0.197 | 0.203 | 0.209 | 5.00 | 5.15 | 5.30 | | |
| D1 | 0.189 | 0.193 | 0.197 | 4.80 | 4.90 | 5.00 | | |
| D2 | 0.154 | 0.161 | 0.169 | 3.90 | 4.10 | 4.30 | | |
| D3 | 0.020 | 0.024 | 0.031 | 0.50 | 0.60 | 0.80 | | |
| D4 | 0.063 | 0.069 | 0.075 | 1.60 | 1.75 | 1.90 | | |
| (d1) | - | 0.016 | - | = | 0.40 | = | | |
| (d2) | - | 0.005 | - | - | 0.125 | - | | |
| Е | 0.238 | 0.244 | 0.250 | 6.05 | 6.20 | 6.35 | | |



Outline Dimensions

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| DIM. | | INCHES | | | MILLIMETERS | | | |
|------|-------|-----------|-------|------|-------------|------|--|--|
| DIM. | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. | | |
| E1 | 0.228 | 0.232 | 0.236 | 5.80 | 5.90 | 6.00 | | |
| E2 | 0.157 | 0.165 | 0.173 | 4.00 | 4.20 | 4.40 | | |
| (E3) | - | 0.144 | = | - | 3.65 | = | | |
| е | | 0.050 BSC | | | 1.27 BSC | | | |
| (K) | 0.039 | - | - | 1.00 | - | - | | |
| L1 | 0.019 | - | 0.043 | 0.48 | - | 1.10 | | |
| L2 | 0.012 | - | 0.031 | 0.30 | - | 0.80 | | |
| M | 0.128 | 0.138 | 0.148 | 3.25 | 3.50 | 3.75 | | |
| Θ | 0° | - | 10° | 0° | - | 10° | | |

Notes

- Dimensioning and tolerancing per ASME Y14.5-2009
- Dimensions D1 and E1 do not include mold flash or gate burrs
- Dimension (XX) means reference only



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